

	Type	Ref #	Hits	Search Text	DBs	Time Stamp	Comments
1	BRS	S1	71	etch\$3 same endpoint same (low with (k or dielectric or constant))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/16 14:02	
2	BRS	S2	30	S1 and @pd<="20030929"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/16 14:13	
3	BRS	S3	5	etch\$3 same endpoint same (low with (k or dielectric or constant)) same (gate with (electrode or dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/16 14:13	
4	BRS	S4	156	etch\$3 same endpoint same (gate with (electrode or dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/16 14:13	
5	BRS	S5	97	S4 and @pd<="20030929"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/16 14:56	
6	BRS	S6	18	DESHMUKH-SHASHANK-C.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/16 15:05	
7	BRS	S7	15	GRIMBERGEN-MICHAEL-N.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/05/16 15:05	